

Features

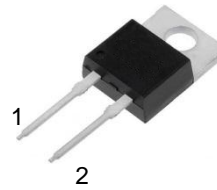
- New Thin Wafer Technology
- Low Forward Voltage Drop (V_F)
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on V_F
- Temperature-independent Switching

V_{RRM}	=	650	V
$I_F (T_C \leq 160^\circ C)$	=	4	A
Q_C	=	11.5	nC

Benefits

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

Package



TO-220-2

Applications

- Switch Mode Power Supplies
- Uninterruptible Power Supplies
- Motor drive, PV Inverter, Wind Power Station



Part Number	Package	Marking
AS4D004065A	TO-220-2	AS4D004065A

Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions	Note
V_{RRM}	Repetitive Peak Reverse Voltage	650	V	$T_C = 25^\circ\text{C}$	
V_{RSM}	Surge Peak Reverse Voltage	650	V	$T_C = 25^\circ\text{C}$	
V_R	DC Blocking Voltage	650	V	$T_C = 25^\circ\text{C}$	
I_F	Forward Current	8 4	A	$T_C \leq 135^\circ\text{C}$ $T_C \leq 160^\circ\text{C}$	
I_{FSM}	Non-Repetitive Forward Surge Current	32	A	$T_C = 25^\circ\text{C}$, $t_p = 8.3\text{ms}$, Half Sine Wave	
P_{tot}	Power Dissipation	60	W	$T_C = 25^\circ\text{C}$	Fig.3
T_J, T_{STG}	Operating Junction and Storage Temperature	-55 to 175	$^\circ\text{C}$		
T_{sold}	Soldering Temperature	260	$^\circ\text{C}$		
	TO-220-2 Mounting Torque	1	Nm	M3 Screw	

Electrical Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
V_F	Forward Voltage	1.28 1.40	1.5 1.6	V	$I_F = 4\text{A}$, $T_J = 25^\circ\text{C}$ $I_F = 4\text{A}$, $T_J = 175^\circ\text{C}$	Fig.1
I_R	Reverse Current	4 20	50 200	μA	$V_R = 650\text{V}$, $T_J = 25^\circ\text{C}$ $V_R = 650\text{V}$, $T_J = 175^\circ\text{C}$	Fig.2
C	Total Capacitance	250 26 19	/	pF	$V_R = 0.1\text{V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{MHz}$ $V_R = 200\text{V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{MHz}$ $V_R = 400\text{V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{MHz}$	Fig.5
Q_C	Total Capacitive Charge	11.5	/	nC	$V_R = 400\text{V}$, $I_F = 4\text{A}$ $di/dt = 200\text{A}/\mu\text{s}$, $T_J = 25^\circ\text{C}$	Fig.4

Thermal Characteristics

Symbol	Parameter	Typ.	Unit	Note
$R_{\theta JC}$	Thermal Resistance from Junction to Case	2.5	$^\circ\text{C}/\text{W}$	Fig.6
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	80	$^\circ\text{C}/\text{W}$	

Typical Performance

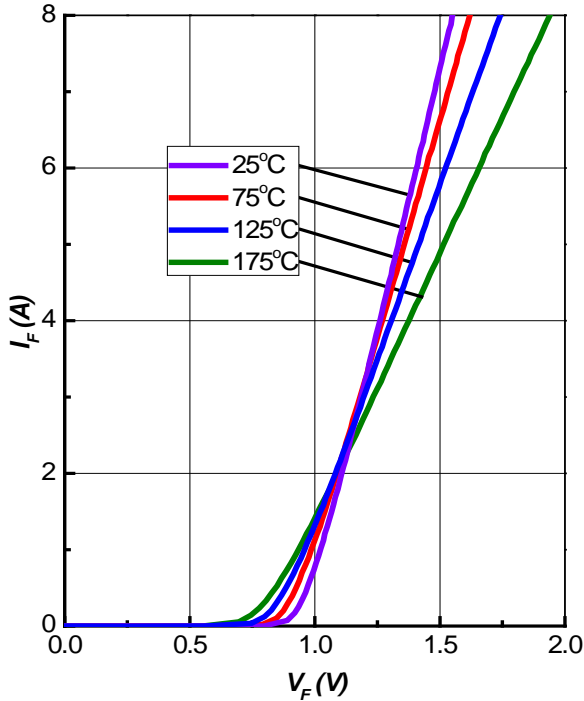


Figure 1. Forward Characteristics

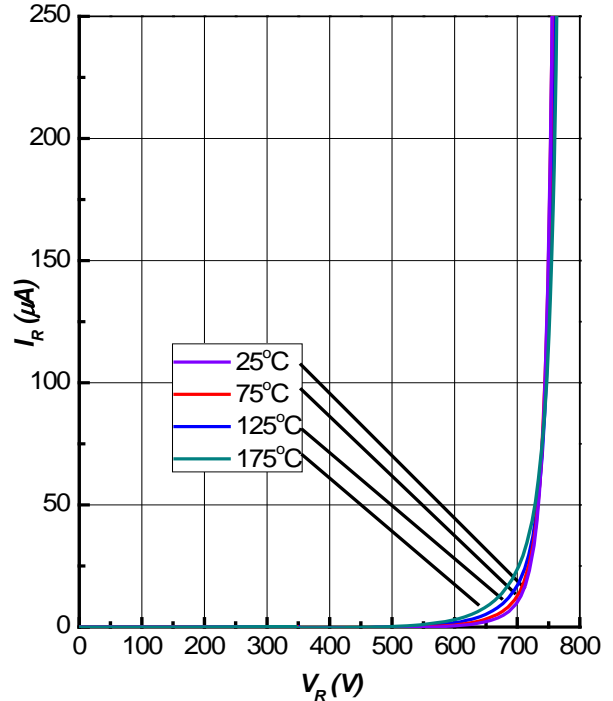


Figure 2. Reverse Characteristics

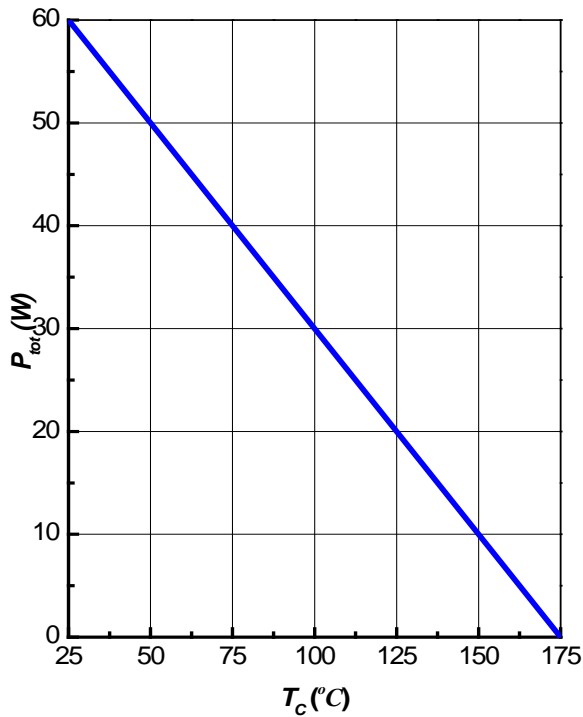


Figure 3. Power Derating

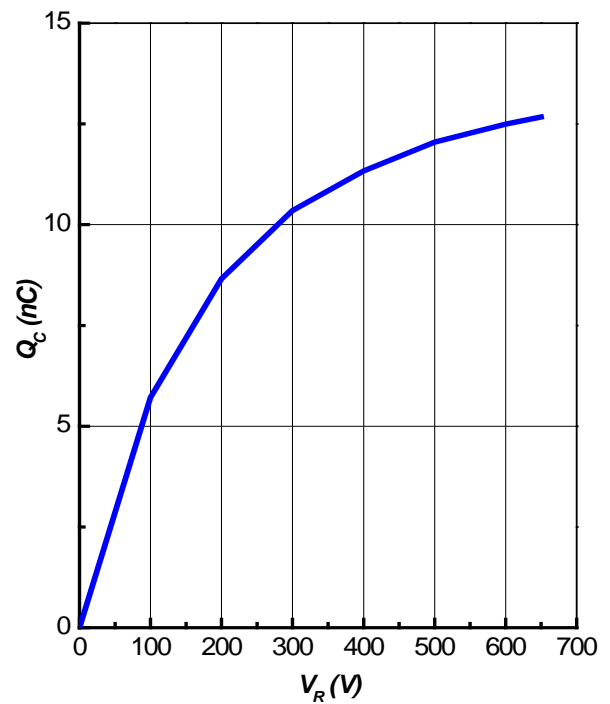


Figure 4. Total Capacitive Charge vs. Reverse Voltage

Typical Performance

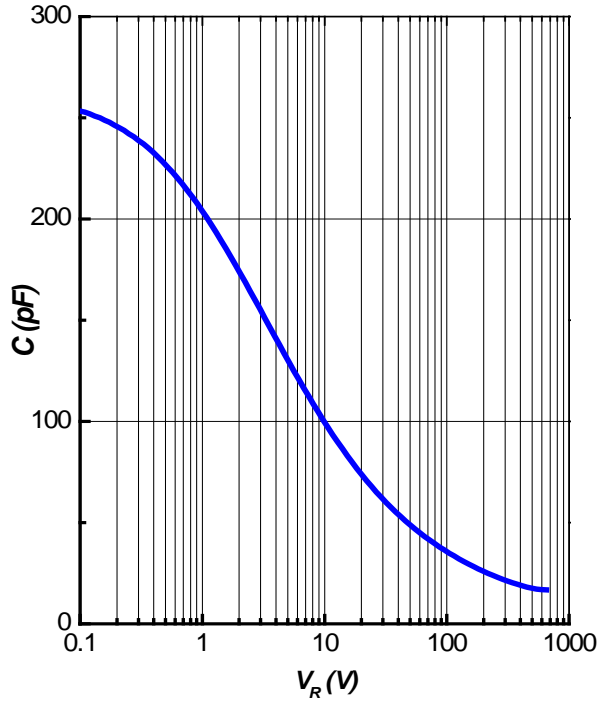


Figure 5. Total Capacitance vs. Reverse Voltage

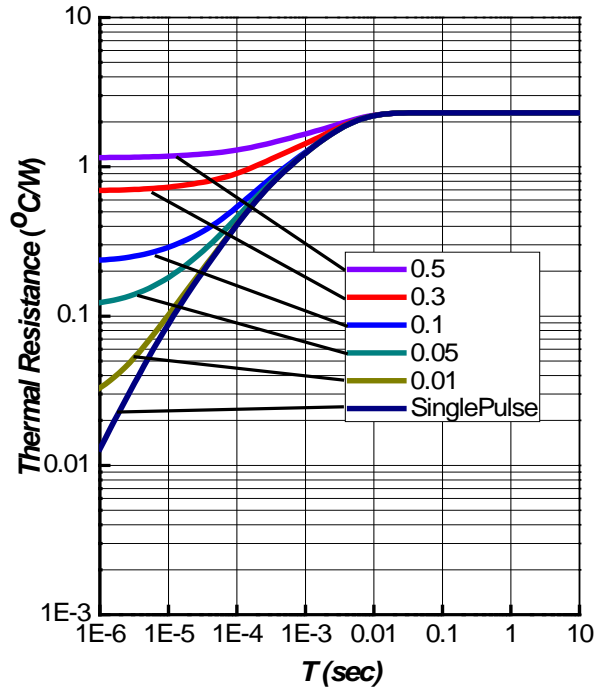
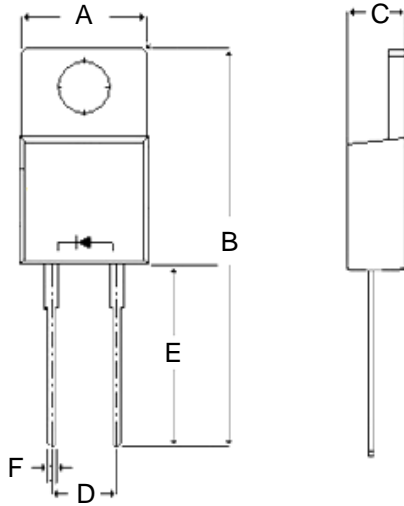


Figure 6. Transient Thermal Impedance

Package Dimensions

Package TO-220-2



Symbol	Min. (mm)	Typ. (mm)	Max. (mm)
A	9.17	10.08	10.91
B	27.00	28.58	30.00
C	3.89	4.50	5.00
D	4.20	5.10	5.80
E	11.70	13.30	14.97
F	0.50	0.80	1.21